

R1200F THRU R2000F



HIGH VOLTAGE FAST RECOVERY RECTIFIERS



FEATURES

- * Low forward voltage drop
- * High current capability
- * High reliability
- * High surge current capability

MECHANICAL DATA

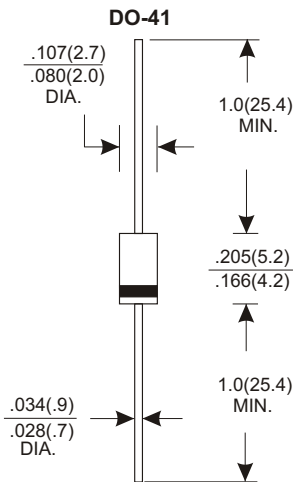
- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Lead: Axial leads, solderable per MIL-STD-202, method 208 guaranteed
- * Polarity: Color band denotes cathode end
- * Mounting position: Any

VOLTAGE RANGE

1200 to 2000 Volts

CURRENT

500m/200m Ampere



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.
 Single phase half wave, 60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

TYPE NUMBER	R1200F	R1500F	R1600F	R1800F	R2000F	UNITS
Maximum Recurrent Peak Reverse Voltage	1200	1500	1600	1800	2000	V
Maximum RMS Voltage	840	1050	1120	1260	1400	V
Maximum DC Blocking Voltage	1200	1500	1600	1800	2000	V
Maximum Average Forward Rectified Current					200	mA
.375"(9.5mm) Lead Length at Ta=50°C	500					
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	30					A
Maximum Instantaneous Forward Voltage at 0.5A D.C.	2.0				3.0	V
Maximum DC Reverse Current Ta=25°C	5.0					μA
at Rated DC Blocking Voltage Ta=100°C	100					μA
Maximum Reverse Recovery Time (Note 1)	500					nS
Typical Junction Capacitance (Note 2)	40					pF
Operating and Storage Temperature Range Tj, Tstg	-65— +150					°C

NOTES:

1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

RATING AND CHARACTERISTIC CURVES (R1200F THRU R2000F)

FIG.1 - TYPICAL REVERSE CHARACTERISTICS

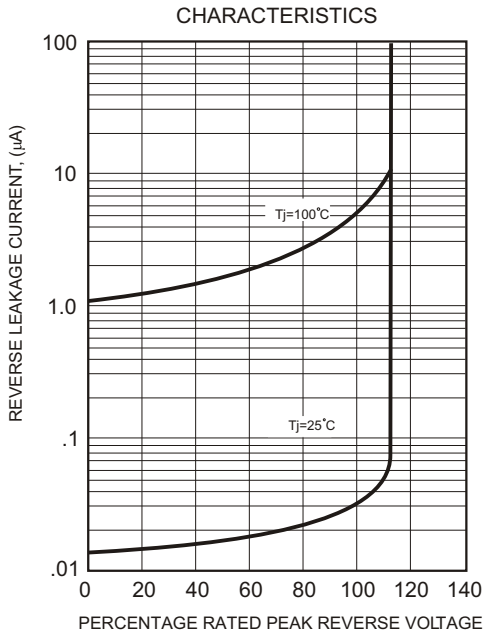


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

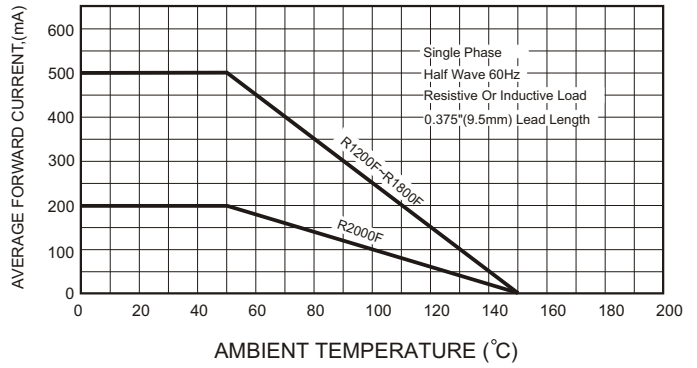


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

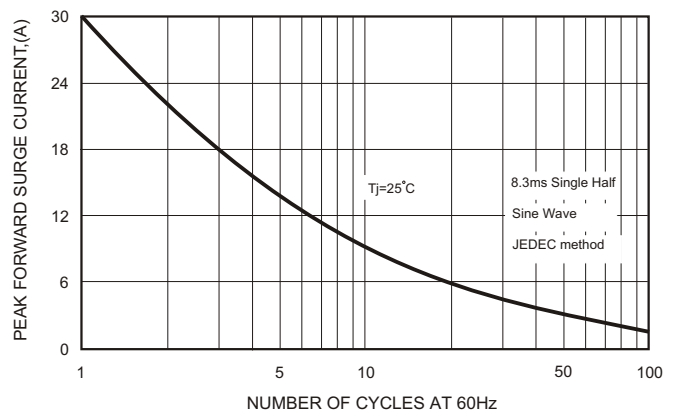
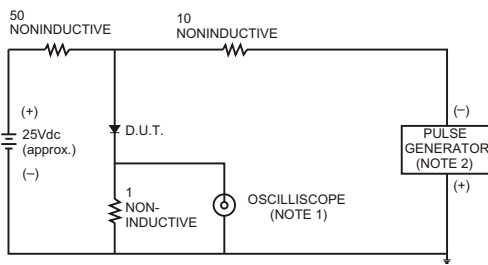


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm, 22pF.
2. Rise Time= 10ns max., Source Impedance= 50 ohms.

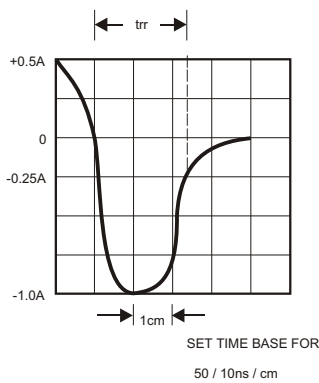


FIG.5-TYPICAL JUNCTION CAPACITANCE

